

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	9	"6583460"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 11:34
L5	13	"6373088"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 11:53
L7	7	(US-20010026004-\$ or US-20020079548-\$).did. or (US-6730581-\$ or US-6187686-\$ or US-6235579-\$ or US-6677632-\$ or US-6373088-\$).did.	US-PGPUB; USPAT	OR	ON	2006/05/12 12:19
L8	4	I7 and memory and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 12:20
S1	17	(polysilicon with barrier) and (oxygen with absorbing)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 05:56
S2	623	gate and (polysilicon with barrier) and (sidewall with nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/11 17:19
S3	9	S2 and (gate with (platinum or iridium or ruthenium or rhodium)) and (barrier with (nitride or carbide or boride))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/13 06:42
S4	12	S2 and (gate with (platinum or iridium or ruthenium or rhodium))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/11 17:30
S5	32	(polysilicon with gate) and (gate with (platinum or iridium or ruthenium or rhodium)) and (gate with barrier with (nitride or carbide or boride))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/11 17:40

## EAST Search History

S6	623	gate and (polysilicon with barrier) and (sidewall with nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/13 06:42
S7	9	S6 and (gate with (platinum or iridium or ruthenium or rhodium)) and (barrier with (nitride or carbide or boride))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/13 06:43
S8	8	(polysilicon with barrier with platinum with (silicon adj nitride))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/11 05:57
S9	4	"6677632"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/12 11:34
S10	3467	257/296.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/16 14:54